



CT1010-W, CT1011-W, CT1012-W, CT1013-W, CT1014-W

CT1015-W, CT1016-W, CT1017-W, CT1018-W, CT1019-W

DC Input 4-Pin Long Mini-Flat Phototransistor Optocoupler

Features

- High isolation 5000 VRMS
- CTR flexibility available see order information
- Extra low coupling capacitance
- DC input with transistor output
- Temperature range - 55 °C to 125 °C
- External creepage distance > 8 mm
- Internal creepage distance > 4.6 mm
- Distances through insulation > 0.4 mm
- Green Package
- Regulatory Approvals
 - UL - UL1577 (E364000)
 - VDE - EN60747-5-5(VDE0884-5)
 - CQC – GB4943.1, GB8898
 - IEC60065, IEC60950

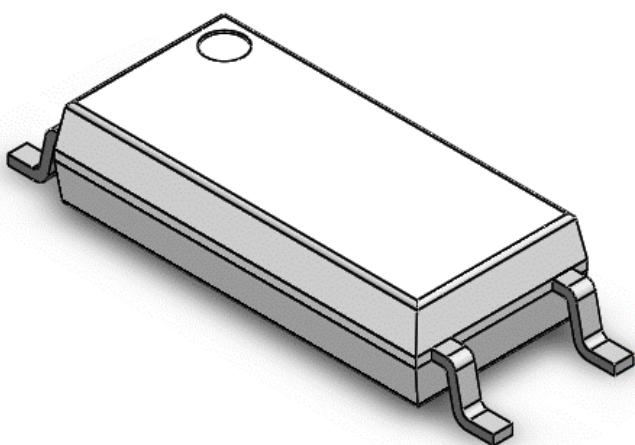
Applications

- Switch mode power supplies
- Computer peripheral interface
- Microprocessor system interface

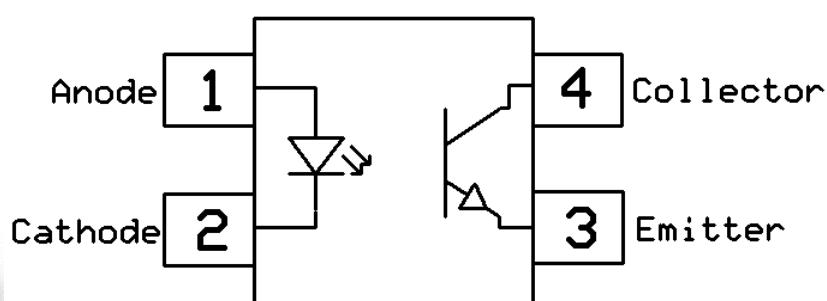
Description

The CT1010-W, CT1011-W, CT1012-W, CT1013-W, CT1014-W, CT1015-W, CT1016-W, CT1017-W, CT1018-W, CT1019-W consists of a photo transistor optically coupled to a gallium arsenide Infrared-emitting diode in a 4-lead SOP Package.

Package Outline



Schematic





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DC Input 4-Pin Long Mini-Flat Phototransistor Optocoupler

Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes
V _{ISO}	Isolation voltage	5000	V _{RMS}	
T _{OPR}	Operating temperature	-55 ~ +125	°C	
T _{STG}	Storage temperature	-55 ~ +150	°C	
T _{SOL}	Soldering temperature	260	°C	

Emitter				
I _F	Forward current	50	mA	
I _{F(TRANS)}	Peak transient current (≤1μs P.W,300pps)	1	A	
V _R	Reverse voltage	6	V	
P _D	Power dissipation	85	mW	

Detector				
P _C	Power dissipation	150	mW	
B _{VCEO}	Collector-Emitter Breakdown Voltage	80	V	
B _{VECO}	Emitter-Collector Breakdown Voltage	7	V	
I _C	Collector Current	50	mA	

Thermal Characteristics

Symbol	Parameters	Ratings	Units	Notes
R _{θJA}	Thermal Resistance Junction-Ambient	445	°C/W	
T _J	Junction temperature	125	°C	



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Electrical Characteristics $T_A = 25^\circ\text{C}$ (unless otherwise specified)

Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
V_F	Forward voltage	$I_F=10\text{mA}$		1.26	1.4	V	
		$I_F=50\text{mA}$	-	1.42	1.5	V	
I_R	Reverse Current	$V_R = 6\text{V}$	-	-	5	μA	
C_{IN}	Input Capacitance	$f= 1\text{kHz}$	-	45	-	pF	

Detector Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
B_{VCEO}	Collector-Emitter Breakdown	$I_C = 100\mu\text{A}$	80	-	-	V	
B_{VECO}	Emitter-Collector Breakdown	$I_E = 100\mu\text{A}$	7	-	-	V	
I_{CEO}	Collector-Emitter Dark Current	$V_{CE}= 20\text{V}, I_F= 0\text{mA}$	-	-	100	nA	

Transfer Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
CTR	Current Transfer Ratio	$CT1012\text{-}W$ $CT1013\text{-}W$ $CT1014\text{-}W$	$I_F= 1\text{mA}, V_{CE}= 5\text{V}$	22	-	-	%
				34	-	-	
				56	-	-	
		$CT1011\text{-}W$ $CT1012\text{-}W$ $CT1013\text{-}W$ $CT1014\text{-}W$	$I_F= 10\text{mA}, V_{CE}= 5\text{V}$	60	-	300	
				63	-	125	
				100	-	200	
				160	-	320	
		$CT1010\text{-}W$ $CT1015\text{-}W$ $CT1016\text{-}W$ $CT1017\text{-}W$ $CT1018\text{-}W$ $CT1019\text{-}W$	$I_F= 5\text{mA}, V_{CE}= 5\text{V}$	50	-	600	
				50	-	150	
				100	-	300	
				80	-	160	
				130	-	260	
				200	-	400	
$V_{CE(\text{SAT})}$	Collector-Emitter Saturation Voltage	$I_F= 10\text{mA}, I_C= 1\text{mA}$	-	-	0.4	V	
R_{IO}	Isolation Resistance	$V_{IO}= 500\text{V}_{\text{DC}}$	5×10^{10}			Ω	
C_{IO}	Isolation Capacitance	$f= 1\text{MHz}$			1	pF	



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Electrical Characteristics $T_A = 25^\circ\text{C}$, $V_{CC} = 5\text{V}$ (unless otherwise specified)

Switching Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
T_{ON}	Turn On Time	$I_C = 5\text{mA}$, $V_{CE} = 5\text{V}$, $R_L = 100\Omega$	-	4.8	22	μs	
T_{OFF}	Turn Off Time		-	4.2	22		
t_r	Rise Time		-	2.7	18		
t_f	Fall Time		-	4	18		



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Typical Characteristic Curves

Forward Current vs. Forward Voltage

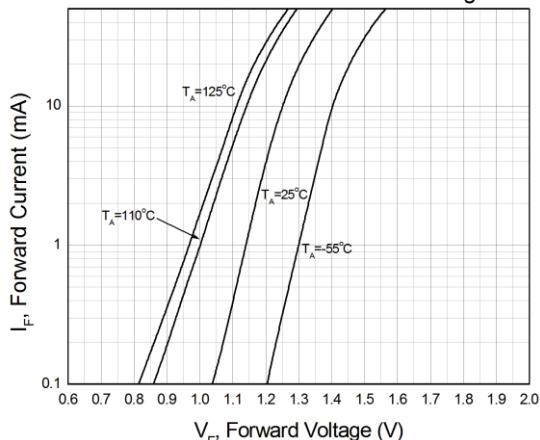


Figure 1

Collector Dark Current vs. Ambient Temperature

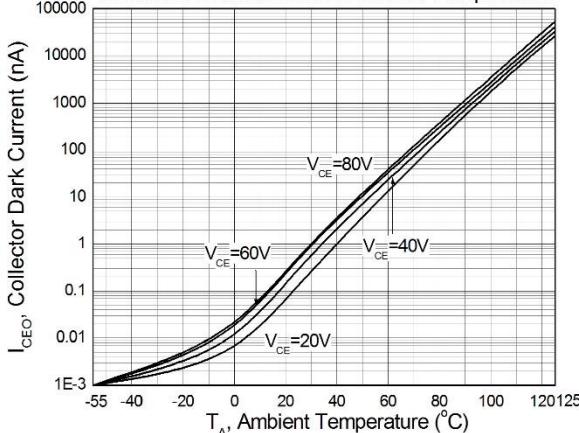


Figure 4

Normalized CTR vs. Forward Current

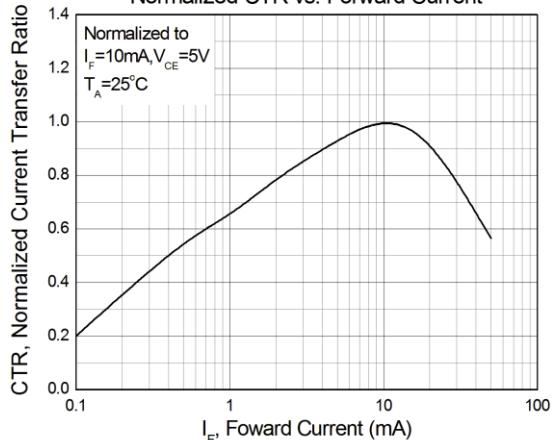


Figure 3

Collector Current vs. Ambient Temperature

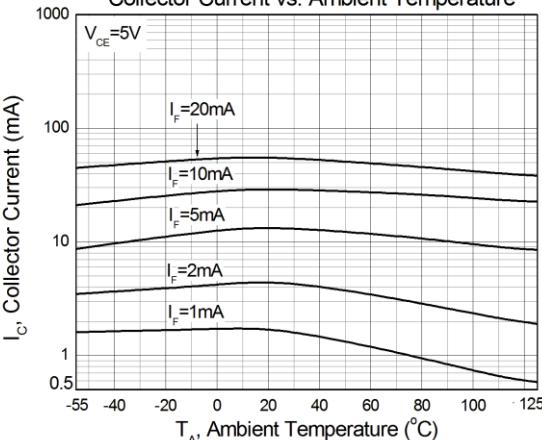


Figure 4

Normalized CTR vs. Ambient Temperature

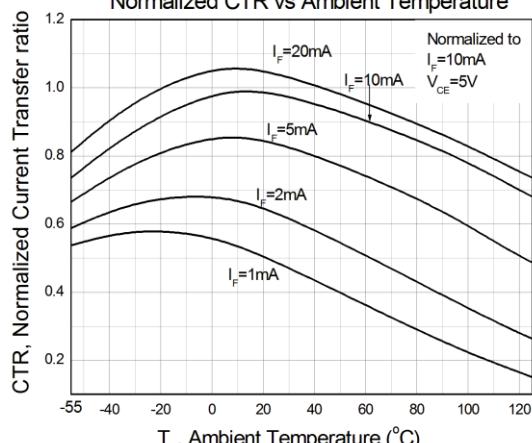


Figure 5

Collector-Emitter Saturation Voltage vs. Collector Current

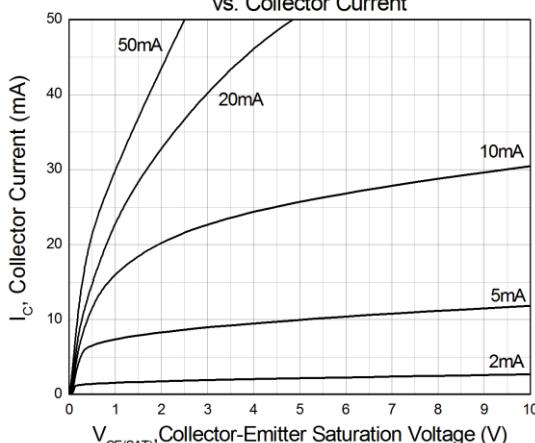


Figure 6



CT1010-W, CT1011-W, CT1012-W, CT1013-W, CT1014-W

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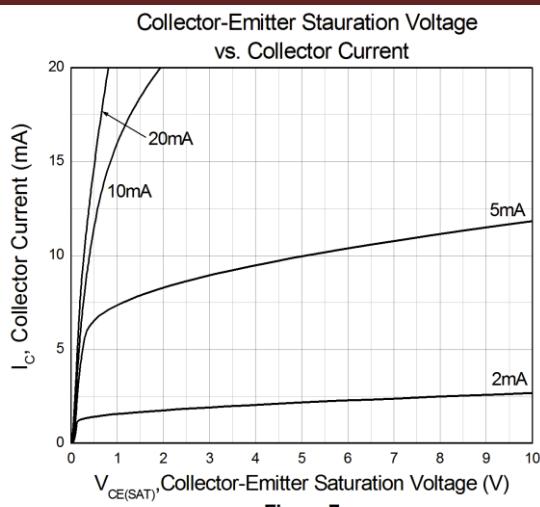


Figure 7

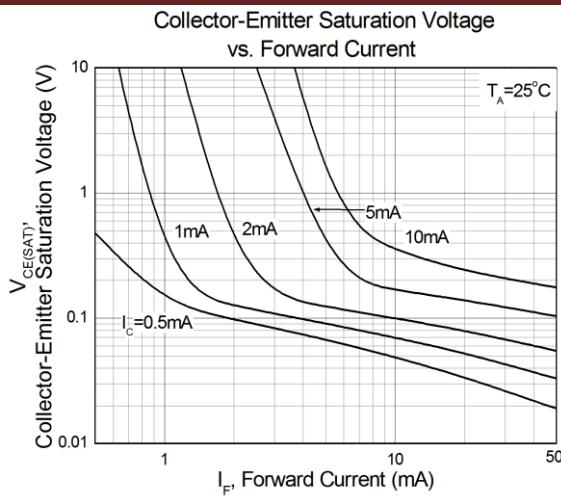


Figure 8

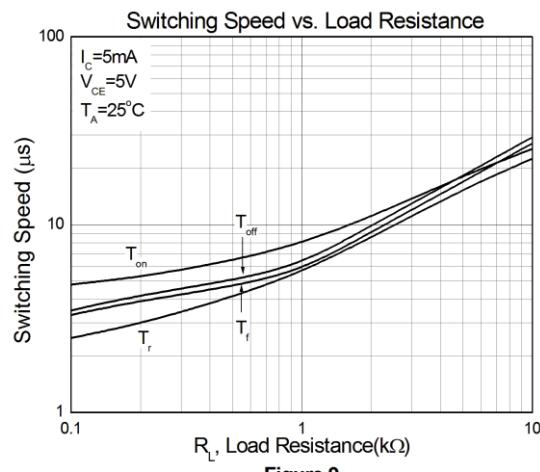


Figure 9

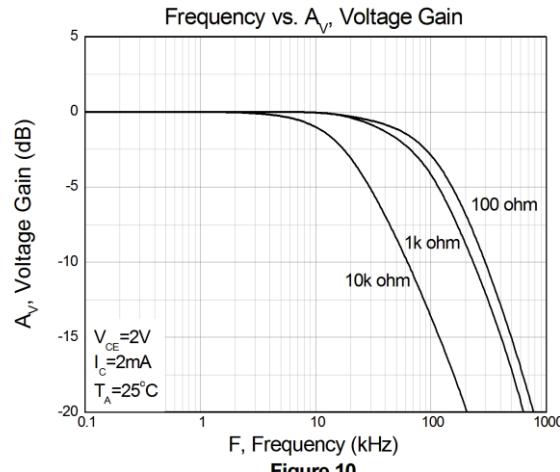


Figure 10

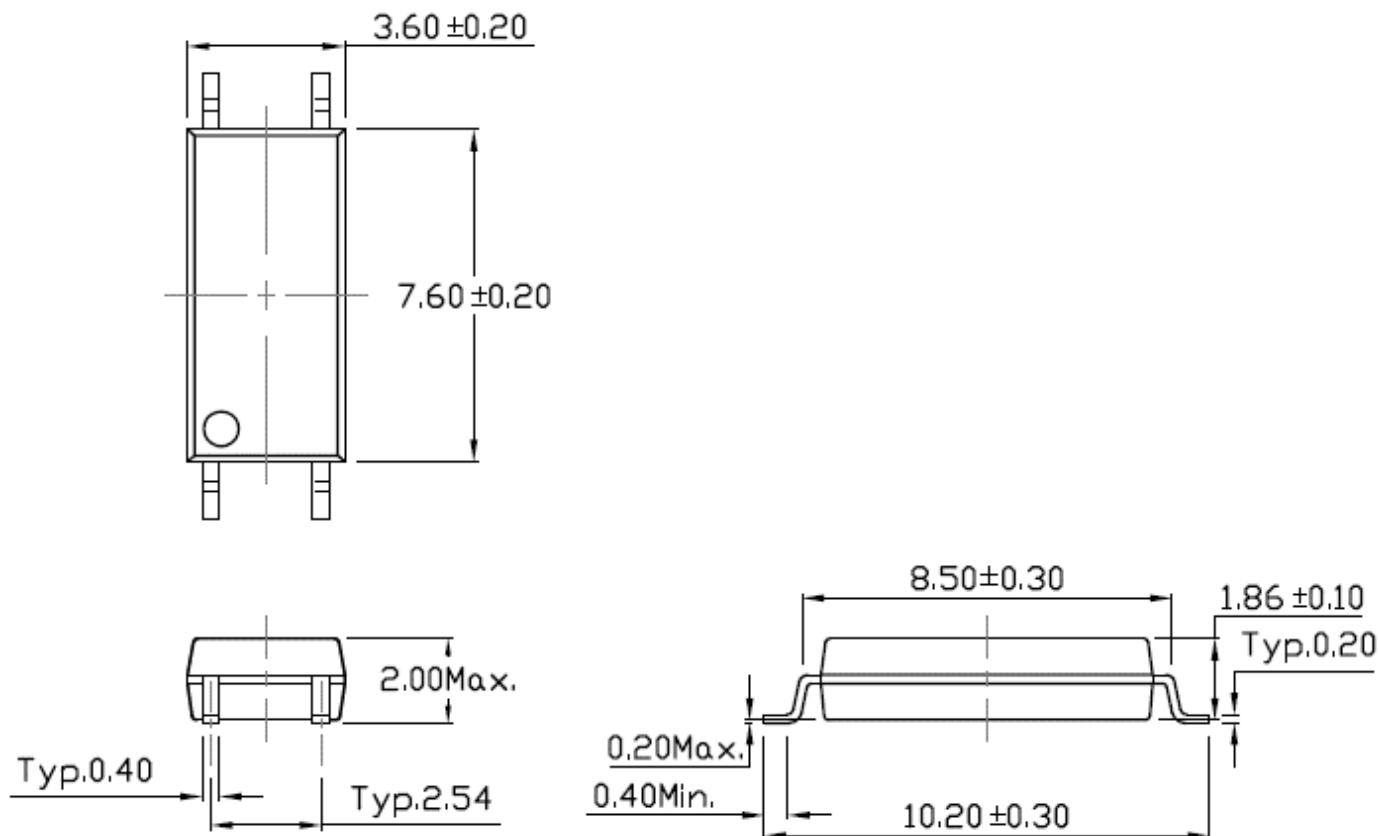


CT1010-W, CT1011-W, CT1012-W, CT1013-W, CT1014-W

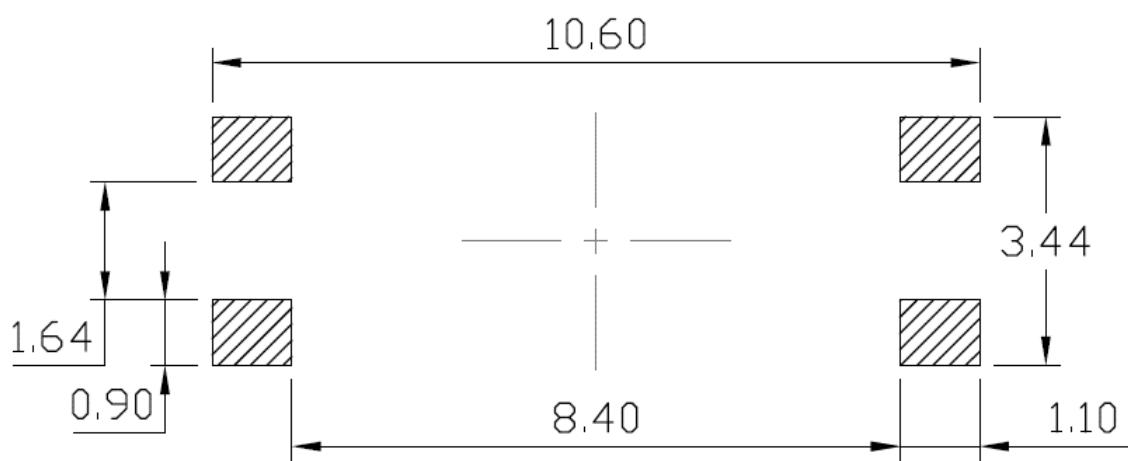
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Package Dimension Dimensions in mm unless otherwise stated



Recommended Solder Mask Dimensions in mm unless otherwise stated





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Marking Information



Note:

- CT : Denotes "CT Micro"
1019 : Part Number
Y : Fiscal Year
V : VDE safety mark (option)
WW : Work Week
K : Manufacturing Code

Ordering Information

CT101X(V)(Y) -W

X = Part No. (0,1,2,3,4,5,6,7,8,9)

V = VDE safety mark option (V or none)

Y = Tape and reel option (T1 or T2)

W = Outline Color (W, White)

Option	Description	Quantity
T1	Surface Mount Lead Forming – With Option 1 Taping	3000Units/Reel
T2	Surface Mount Lead Forming – With Option 2 Taping	3000Units/Reel



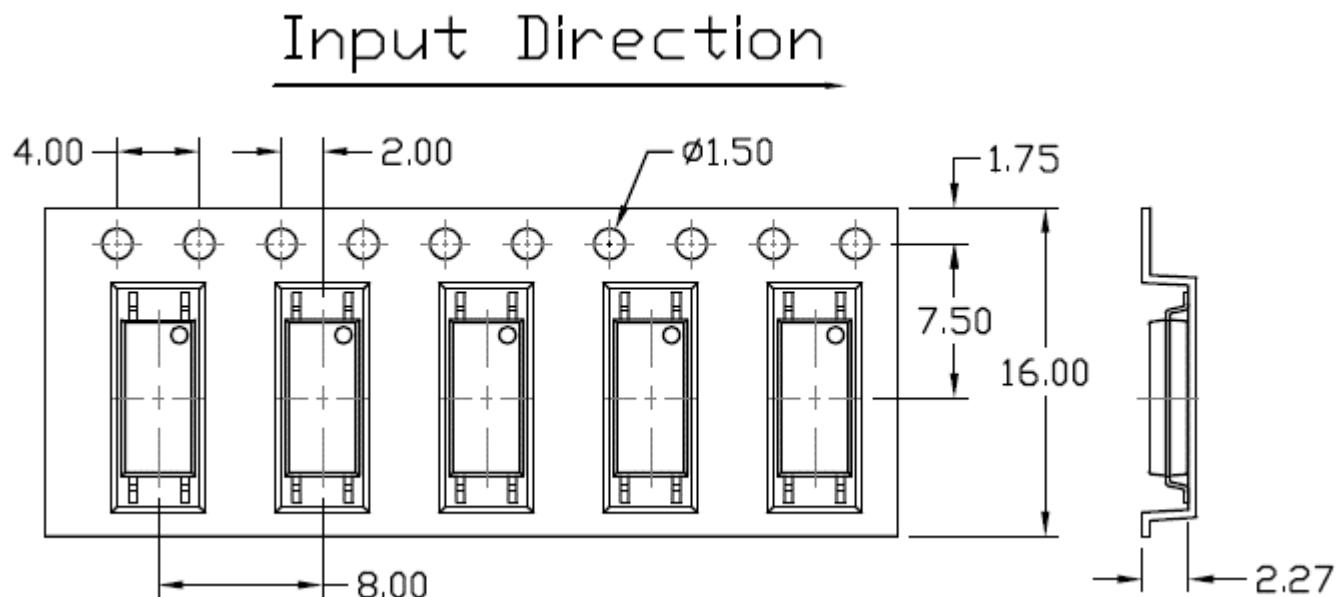
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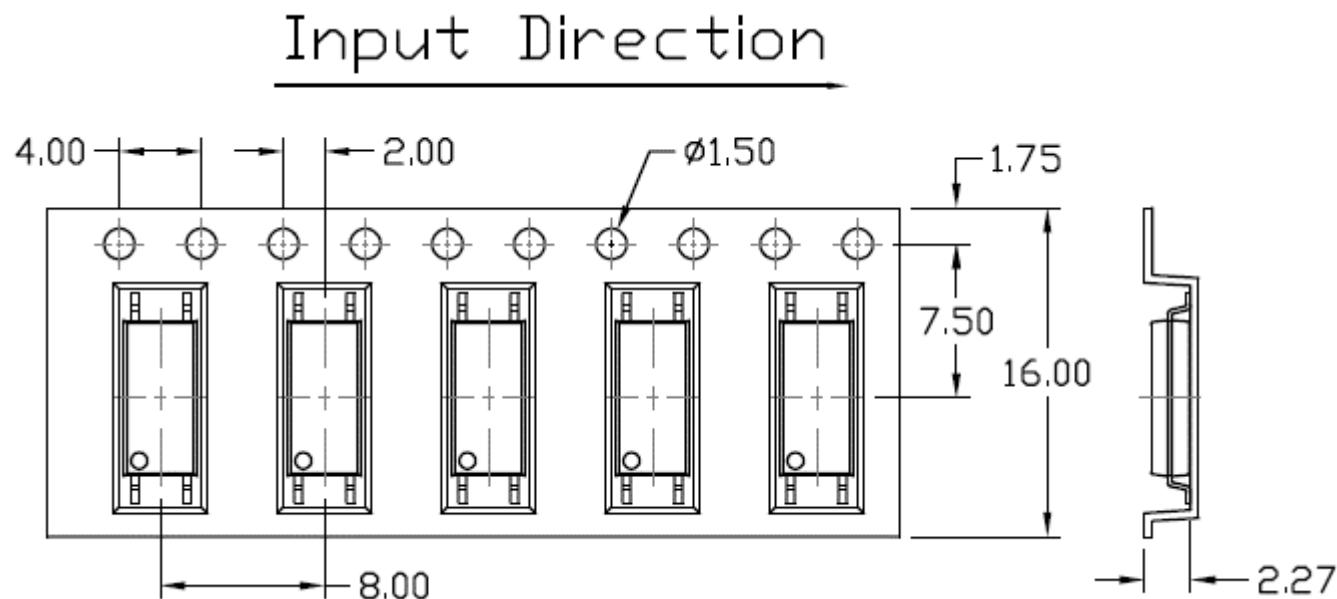
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Carrier Tape Specifications Dimensions in mm unless otherwise stated

Option T1



Option T2





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Wave soldering (JEDEC22A111 compliant)

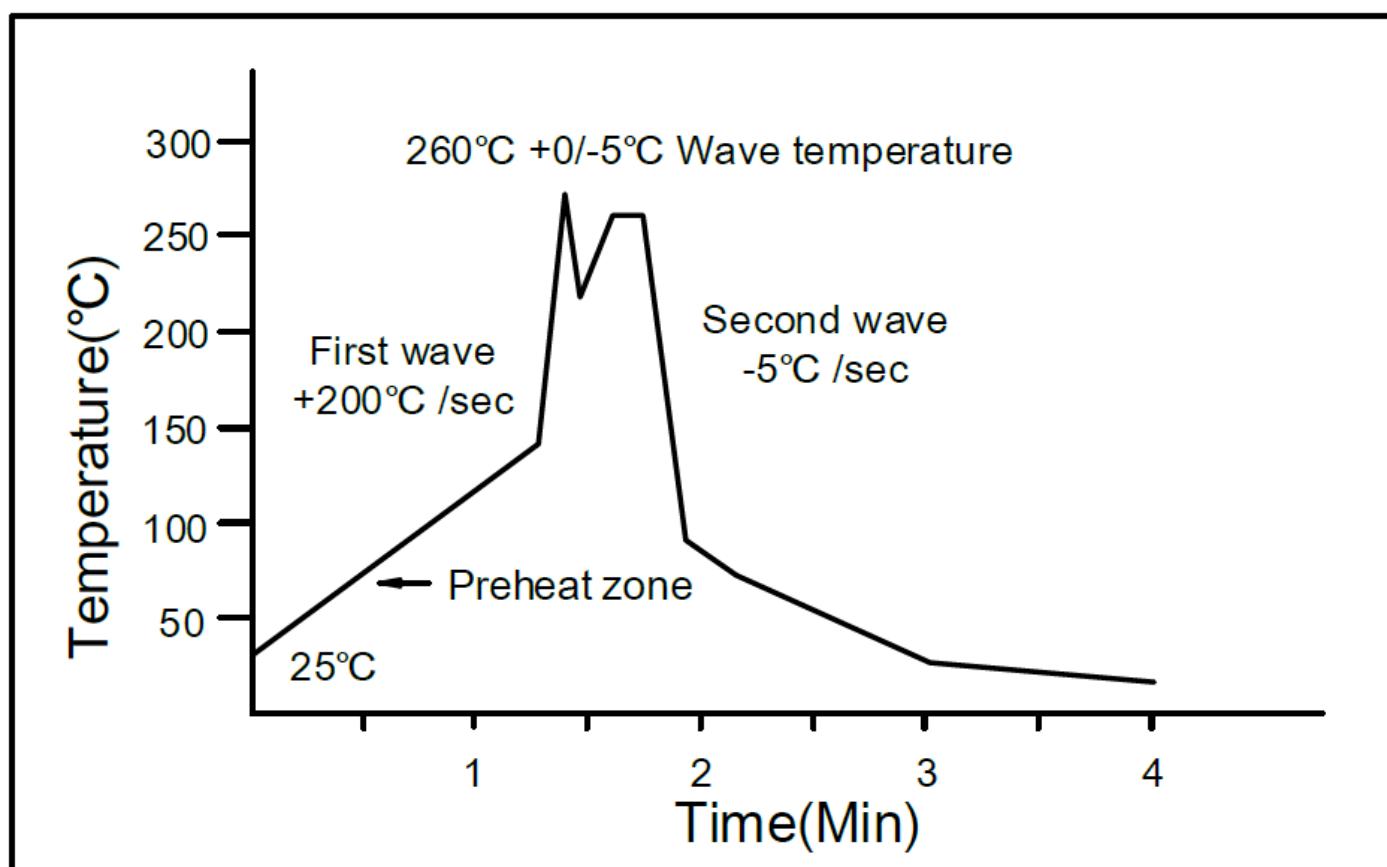
One time soldering is recommended within the condition of temperature.

Temperature: 260+0/-5°C.

Time: 10 sec.

Preheat temperature: 25 to 140°C.

Preheat time: 30 to 80 sec.



Hand soldering by soldering iron

Allow single lead soldering in every single process.

One time soldering is recommended. Temperature: 350+0/-5°C

Time: 3 sec max.

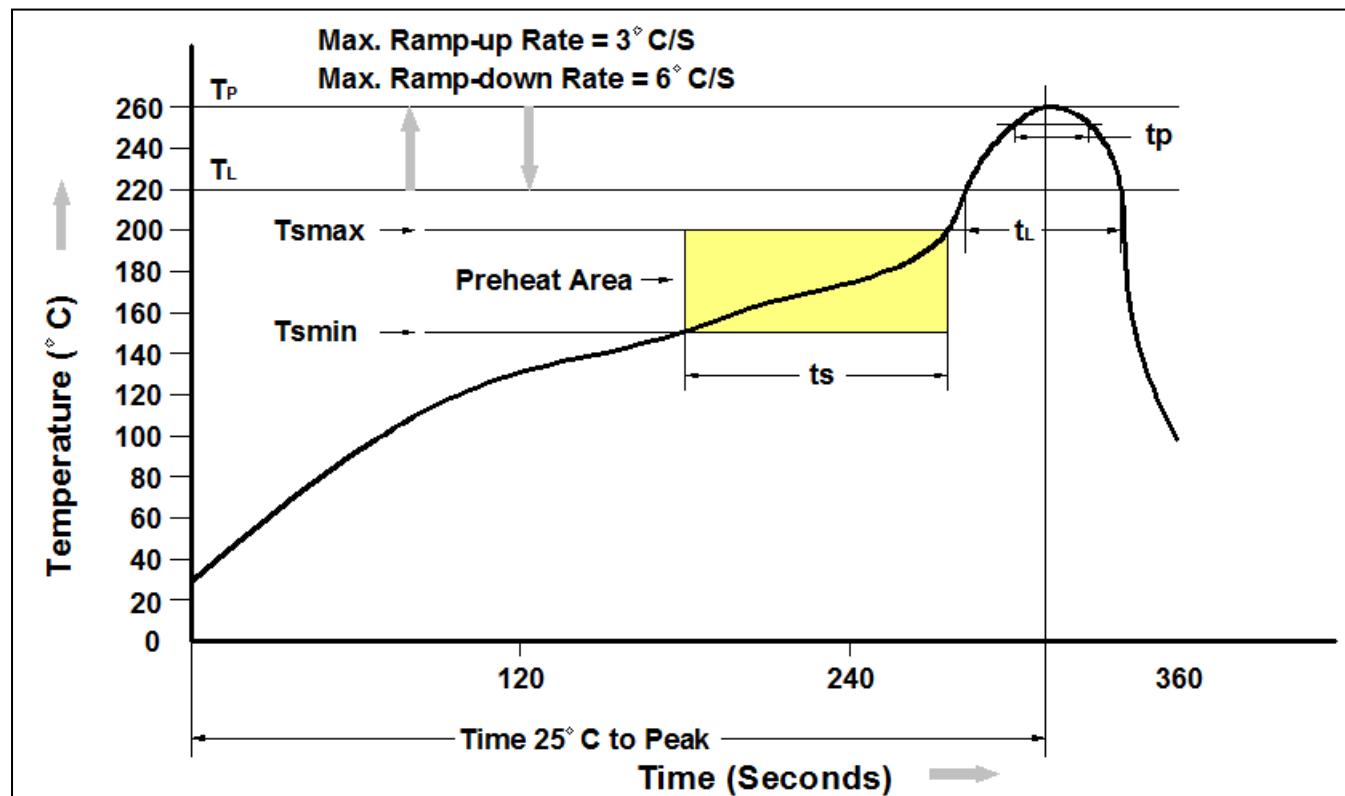


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Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (T _{smin})	150°C
Temperature Max. (T _{smax})	200°C
Time (t _s) from (T _{smin} to T _{smax})	60-120 seconds
Ramp-up Rate (t _L to t _P)	3°C/second max.
Liquidous Temperature (T _L)	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.



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